NSN 5961-01-379-4684

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View Online at https://aerobasegroup.com/nsn/5961-01-379-4684 **Inclosure Material:** Plastic **Overall Length:** Between 0.110 inches and 0.120 inches **Overall Height:** Between 0.030 inches and 0.047 inches **Overall Width:** Between 0.083 inches and 0.098 inches **Internal Configuration:** Junction contact **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 collector to emitter voltage, dc with base short-circuited to emitter and 45.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 500.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 350.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 beam lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: